

isc N-Channel MOSFET Transistor

P5506BDA

• FEATURES

- Static drain-source on-resistance:
 $R_{DS(on)} \leq 55m\Omega$
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

• DESCRIPTION

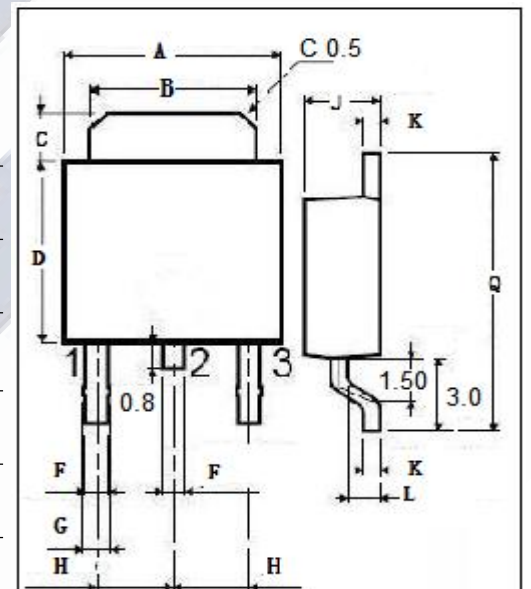
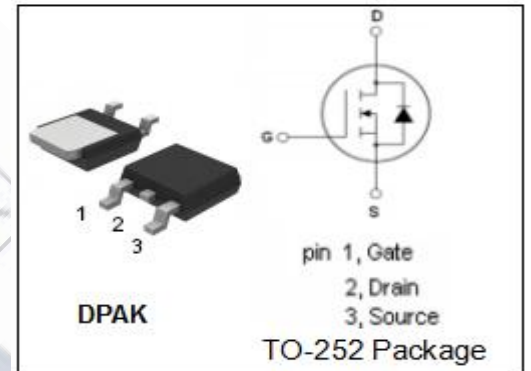
- Switching applications

• ABSOLUTE MAXIMUM RATINGS($T_a=25^\circ C$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{DSS}	Drain-Source Voltage	60	V
V_{GS}	Gate-Source Voltage	± 20	V
I_D	Drain Current-Continuous@ $T_c=25^\circ C$	15	A
I_{DM}	Drain Current-Single Pulsed	30	A
P_D	Total Dissipation @ $T_c=25^\circ C$	27	W
T_j	Max. Operating Junction Temperature	150	$^\circ C$
T_{stg}	Storage Temperature	-55~150	$^\circ C$

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th(j-c)}$	Channel-to-case thermal resistance	4.6	$^\circ C/W$



DIM	mm	
	MIN	MAX
A	6.40	6.60
B	5.20	5.40
C	1.15	1.35
D	5.70	6.10
F	0.65	
G	0.75	
H	2.10	2.50
J	2.10	2.40
K	0.40	0.60
L	0.90	1.10
Q	9.90	10.1

isc N-Channel MOSFET Transistor**P5506BDA****ELECTRICAL CHARACTERISTICS** $T_C=25^{\circ}\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{GS}=0V; I_D=250\ \mu\text{A}$	60			V
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS}=V_{GS}; I_D=250\ \mu\text{A}$	1.3		2.3	V
$R_{DS(on)}$	Drain-Source On-Resistance	$V_{GS}=10V; I_D=10A$			55	$m\Omega$
I_{GSS}	Gate-Source Leakage Current	$V_{DS}=0V; V_{GS}=\pm 20V$			± 100	nA
I_{DSS}	Drain-Source Leakage Current	$V_{DS}=48V; V_{GS}=0V$			1	μA
		$V_{DS}=40V; V_{GS}=0V; T_C=125^{\circ}\text{C}$			10	μA
V_{SD}	Diode forward voltage	$I_{SD}=10A, V_{GS}=0V$			1.2	V

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